



## DDTD (LO-R1 SERIES) C

#### NPN PRE-BIASED SMALL SIGNAL TRANSISTOR IN SOT23

### Features

- Epitaxial Planar Die Construction
- Complementary PNP Types Available (DDTB)
- Built-In Biasing Resistors
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)

/N R1 (NOM) R2 (NOM)	
122LC 0.22kΩ 10kΩ	
142JC 0.47kΩ 10kΩ	
122TC 0.22kΩ OPEN	
142TC 0.47kΩ OPEN	
SOT23	OUT 3 C B R1 F2 E IN GND
Top View	Device Schematic

### Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DDTD122LC -7-F	AEC-Q101	N75	7	8	3,000
DDTD142JC -7-F	AEC-Q101	N76	7	8	3,000
DDTD122TC -7-F	AEC-Q101	N77	7	8	3,000
DDTD142TC -7-F	AEC-Q101	N78	7	8	3,000

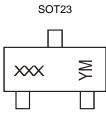
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

 See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## Marking Information



 $\begin{array}{l} XXX = \mbox{Product Type Marking Code, See Table Above} \\ YM = \mbox{Date Code Marking} \\ Y = \mbox{Year ex: } B = 2014 \\ M = \mbox{Month ex: } 9 = \mbox{September} \end{array}$ 

Date Code Key

Date Code Rey												
Year	2014	20	15	2016	2017	201	8	2019	2020	202	1	2022
Code	В	(		D	E	F		G	Н			J
Month	Jan	Feb	Mar	Apr	Mav	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



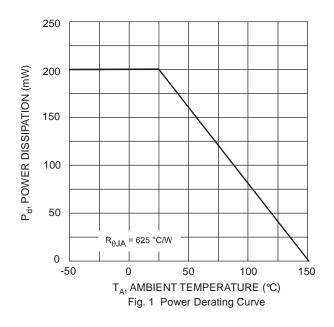
## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteris	Symbol	Value	Unit	
Supply Voltage <pin: (2)="" (3)="" to=""></pin:>		V <sub>CC</sub>	50	V
Input Voltage <pin: (1)="" (2)<="" td="" to=""><td>DDTD122LC DDTD142JC</td><td>V<sub>IN</sub></td><td>-5 to +6 -5 to +6</td><td>V</td></pin:>	DDTD122LC DDTD142JC	V <sub>IN</sub>	-5 to +6 -5 to +6	V
Input Voltage <pin: (1)<="" (2)="" td="" to=""><td>DDTD122TC DDTD142TC</td><td>V<sub>EBO (MAX)</sub></td><td>5</td><td>V</td></pin:>	DDTD122TC DDTD142TC	V <sub>EBO (MAX)</sub>	5	V
Output Current		lc	500	mA

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	200	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	R <sub>0JA</sub>	625	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Note: 5. Mounted on FR4 PC board with recommended pad layout.





## Electrical Characteristics - R1, R2 Types (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Input Voltage	DDTD122LC DDTD142JC	V <sub>I(off)</sub>	0.3 0.3		_	V	V <sub>CC</sub> = 5V, I <sub>O</sub> = 100µA
	DDTD122LC DDTD142JC	V <sub>l(on)</sub>			2.0 2.0	v	$V_{O} = 0.3V, I_{O} = 20mA$ $V_{O} = 0.3V, I_{O} = 20mA$
Output Voltage		V <sub>O(on)</sub>		_	0.3V	V	$I_{O}/I_{I} = 50 \text{mA}/2.5 \text{mA}$
Input Current	DDTD122LC DDTD142JC	I <sub>I</sub>			28 13	mA	V <sub>I</sub> = 5V
Output Current		I <sub>O(off)</sub>	_	—	0.5	μA	$V_{CC} = 50V, V_I = 0V$
DC Current Gain	DDTD122LC DDTD142JC	GI	56 56				V <sub>O</sub> = 5V, I <sub>O</sub> = 50mA
Gain-Bandwidth Product (Note 6)		f⊤		200	_	MHz	V <sub>CE</sub> = 10V, I <sub>E</sub> = 5mA, f = 100MHz

# Electrical Characteristics - R1- Only, R2- Only Types (@T<sub>A</sub> = +25°C, unless otherwise specified.)

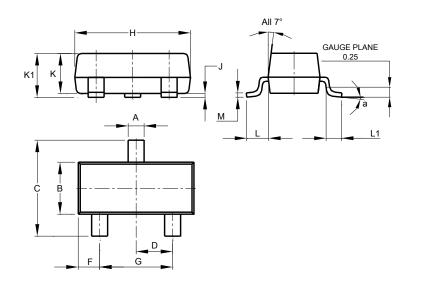
Characteristic		Symbol	Min	Тур	Мах	Unit	Test Condition
Collector-Base Breakdown Voltage		BV <sub>CBO</sub>	50		_	V	I <sub>C</sub> = 50μA
Collector-Emitter Breakdown Voltage		BV <sub>CEO</sub>	40	_	_	V	I <sub>C</sub> = 1mA
Emitter-Base Breakdown Voltage	DDTD122TC DDTD142TC	BV <sub>EBO</sub>	5		_	V	Ι <sub>Ε</sub> = 50μΑ Ι <sub>Ε</sub> = 50μΑ
Collector Cut-Off Current		I <sub>CBO</sub>	_		0.5	μA	$V_{CB} = 50V$
Emitter Cut-Off Current	DDTD122TC DDTD142TC	I <sub>EBO</sub>			0.5 0.5	μA	V <sub>EB</sub> = 4V
Collector-Emitter Saturation Voltage		V <sub>CE(sat)</sub>	—	—	0.3	V	I <sub>C</sub> = 50mA, I <sub>B</sub> = 2.5mA
DC Current Transfer Ratio	DDTD122TC DDTD142TC	h <sub>FE</sub>	100 100	250 250	600 600		I <sub>C</sub> = 5mA, V <sub>CE</sub> = 5V
Gain-Bandwidth Product (Note 6)		f⊤		200		MHz	V <sub>CE</sub> = 10V, I <sub>E</sub> = -5mA, f = 100MHz

Note: 6. Transistor – For Reference Only



# **Package Outline Dimensions**

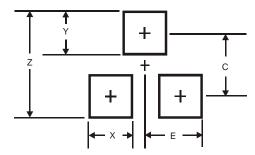
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT23									
Dim	Min	Max	Тур							
Α	0.37	0.51	0.40							
В	1.20	1.40	1.30							
С	2.30	2.50	2.40							
D	0.89	1.03	0.915							
F	0.45	0.60	0.535							
G	1.78	2.05	1.83							
н	2.80	3.00	2.90							
J	0.013	0.10	0.05							
К	0.890	1.00	0.975							
K1	0.903	1.10	1.025							
L	0.45	0.61	0.55							
L1	0.25	0.55	0.40							
М	0.085	0.150	0.110							
а	8°									
All	Dimens	ions in	mm							

# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
Е	1.35



#### IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

#### LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2015, Diodes Incorporated

#### www.diodes.com



单击下面可查看定价,库存,交付和生命周期等信息

>>Diodes Incorporated(达尔科技)